



NPN SURFACE MOUNT SMALL SIGNAL TRANSISTOR IN SOT23

Features

- Ideally Suited for Automatic Insertion
- Complementary PNP Types Available (BC856 BC858)
- For switching and AF Amplifier Applications
- Lead Free, RoHS Compliant (Note 1)
- Halogen and Antimony Free "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

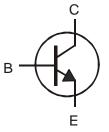
Mechanical Data

- Case: SOT-23
- UL Flammability Rating 94V-0
- Case material: molded Plastic "Green" Compound
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.008 grams (Approximate)

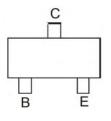
SOT23







Device Symbol



Top View Pin-Out

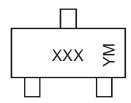
Ordering Information (Note 3 & 4)

Product	Marking	Reel size (inches)	Quantity per reel
BC846A-7-F	K1Q	7	3,000
BC846B-7-F	K1R	7	3,000
BC846BQ-7-F	K1R	7	3,000
BC846B-13-F	K1R	13	10,000
BC847A-7-F	K1Q	7	3,000
BC847AQ-7-F	K1Q	7	3,000
BC847A-13-F	K1Q	13	10,000
BC847B-7-F	K1R	7	3,000
BC847BQ-7-F	K1R	7	3,000
BC847B-13-F	K1R	13	10,000

Product	Marking	Reel size (inches)	Quantity per reel
BC847C-7-F	K1M	7	3,000
BC847C-13-F	K1M	13	10,000
BC848A-7-F	K1Q	7	3,000
BC848B-7-F	K1R	7	3,000
BC848B-13-F	K1R	13	10,000
BC848C-7-F	K1M	7	3,000
BC848CQ-7-F	K1M	7	3,000

- 1. No purposefully added lead.
- 2. Diodes Inc.'s "Green" Policy can be found on our website at http://www.diodes.com
- 3. Tape width is 8mm. For more packaging details, go to our website at http://www.diodes.com.
 4. Products with Q-suffix are automotive grade. All other products are commercial grade.

Marking Information



XXX = Product Type Marking Code, YM = Date Code Marking Y = Year ex: X = 2010M = Month ex: 9 = September

Date Code Key

Year	2010	20	011	2012	2	2013	2014		2015	2016		2017
Code	Χ		Υ	Z		Α	В		С	D		Е
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings @T_A = 25°C unless otherwise specified

Character	istic	Symbol	Value	Unit
	BC846		80	
Collector-Base Voltage	BC847	V_{CBO}	50	V
	BC848		30	
	BC846		65	
Collector-Emitter Voltage	BC847	V_{CEO}	45	V
	BC848		30	
Emitter-Base Voltage	BC846, BC847	V	6.0	M
Emilier-base voltage	BC848	V _{EBO}	5.0	V
Continuous Collector Current		Ic	100	mA
Peak Collector Current		I _{CM}	200	mA
Peak Emitter Current		I _{EM}	200	mA

Thermal Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	P_D	300	mW
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	417	°C/W
Operating and Storage Temperature Range		$T_{J,}T_{STG}$	-65 to +150	°C

Notes: 5. For a device surface mounted on minimum recommended pad layout FR4 PCB with high coverage of single sided 1oz copper in still air conditions; the device is measured when operating in a steady-state condition.



Electrical Characteristics @TA = 25°C unless otherwise specified

Characteristic			Symbol	Min	Тур	Max	Unit	Test Condition	
BC846			80						
Collector-Base Breakdown Voltage		BC847	BV _{CBO}	50	-	-	V	$I_C = 10\mu A$	
	•	BC848		30				-	
0 11 1 5 11 5 11	\ / L	BC846		65					
Collector-Emitter Breakdown	Voltage	BC847	BV _{CEO}	45	-	-	V	$I_C = 10mA$	
(Note 6)		BC848	020	30	1				
Freitter Bees Breekdeur Va	14	BC846 / BC847	D) /	6		_	.,	1 4 .	
Emitter-Base Breakdown Vo	itage	BC848	BV _{EBO}	5	-	-	V	$I_E = 1\mu A$	
Collector Cutoff Current			I _{CBO}	_	_	15	μA	V _{CB} = 40V	
Collector Cutoff Current			iCBO	,	_	5	μΛ	V _{CB} = 30V, T _A =150°C	
		BC846				15		V _{CE} = 80V	
Collector Emitter Cutoff Curr	ent	BC847	I _{CES}	-	-	15	nA	V _{CE} = 50V	
		BC848				15		V _{CE} = 30V	
Small Signal Current Gain	BC846A / E	3C847A / BC848A			200				
(Note 6)	BC846B / E	3C847B / BC848B	h _{fe}	-	330	-	-		
(Note 6)	BC847	7C / BC848C			600				
Input Impedance	BC846A / E	3C847A / BC848A			2.7				
(Note 6)	BC846B / E	BC846B / BC847B / BC848B		-	4.5	-	kΩ		
(Note 6)	BC847	7C / BC848C	h _{ie}		8.7			$I_{C} = 2.0 \text{mA}, V_{CE} = 5 \text{V}$	
Outrout Admitton	BC846A / BC847A / BC848A		h _{oe}	ı	18		μS	f=1.0kHz	
Output Admittance (Note 6)	BC846B / BC847B / BC848B				30	-			
(Note 6)	BC847C / BC848C				60				
Davieras Valtera Transfer	BC846A / E	3C847A / BC848A			1.5x10 ⁻⁴				
Reverse Voltage Transfer Ratio (Note 6)	BC846B / BC847B / BC848B		h _{re}	-	2x10 ⁻⁴	-	-		
Kallo (Note 6)	BC847	7C / BC848C			3x10 ⁻⁴				
	BC846A / E	3C847A / BC848A		110	180	220			
DC Current Gain (Note 6)	BC846B / BC847B / BC848B		h_{FE}	200	290	450	-	$I_C = 2.0 \text{mA}, V_{CE} = 5 \text{V}$	
		7C / BC848C		420	520	800			
Collector-Emitter Saturation	Voltage		V _{CE(sat)}	_	90	250	mV	$I_C = 10mA, I_B = 0.5mA$	
(Note 6)			VCE(sat)		200	600	111.0	$I_C = 100 \text{mA}, I_B = 5.0 \text{mA}$	
Base-Emitter Turn-On Voltag	re(Note 6)		V _{BE(on)}	580	660	700	mV	$I_C = 2mA$, $V_{CE} = 5V$	
Base-Emilier Turn-On Voltag	JC(1401C 0)		vBE(on)	-	-	770	1117	$I_C = 10$ mA, $V_{CE} = 5$ V	
Base-Emitter Saturation Volt	age(Note 6)		V _{BE(sat)}	_	700	_	mV	$I_C = 10 \text{mA}, I_B = 0.5 \text{mA}$	
Base-Emitter Saturation Voltage(Note 6)		VBE(sat)		900		1117	$I_C = 100 \text{mA}, I_B = 5 \text{mA}$		
Output Capacitance		C_{obo}	-	3	-	pF	V _{CB} = 10V, f = 1.0MHz		
Transition Frequency		f _T	100	300	-	MHz	$V_{CE} = 5V$, $I_C = 10mA$, $f = 100MHz$		
Noise Figure			NF	-	2	10	dB	V_{CE} =5V, I_{C} =200 μ A R_{S} =2 $k\Omega$, f=1 k Hz Δ f=200Hz	

Note:

6. Short duration pulse test used to minimize self-heating effect.



Typical Electrical Characteristics

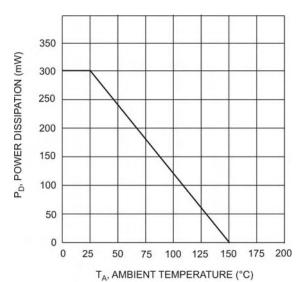
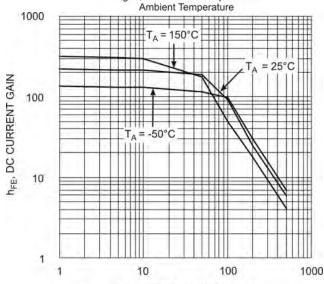
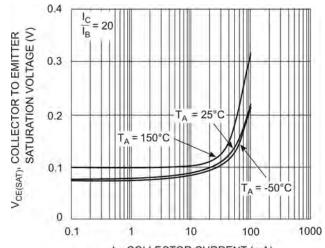


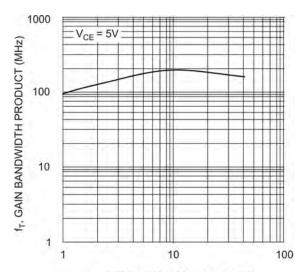
Fig. 1, Max Power Dissipation vs
Ambient Temperature



I_C, COLLECTOR CURRENT (mA) Fig. 3, DC Current Gain vs. Collector Current



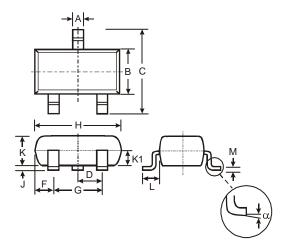
I_C, COLLECTOR CURRENT (mA)
Fig. 2 Collector Emitter Saturation Voltage
vs. Collector Current



I_C, COLLECTOR CURRENT (mA)
Fig. 4, Gain Bandwidth Product vs Collector Current

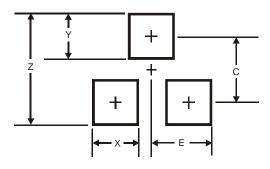


Package Outline Dimensions



SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.903	1.10	1.00				
K 1	-	•	0.400				
L	0.45	0.61	0.55				
М	0.085	0.18	0.11				
α	0°	8°	-				
All	All Dimensions in mm						

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35



IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices-or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2011, Diodes Incorporated

www.diodes.com